

# Supplementary Information // Embedding of atoms into the holey site of the $C_6N_6$ and $C_6N_8$ porous carbon nitride monolayers with tunable electronic properties

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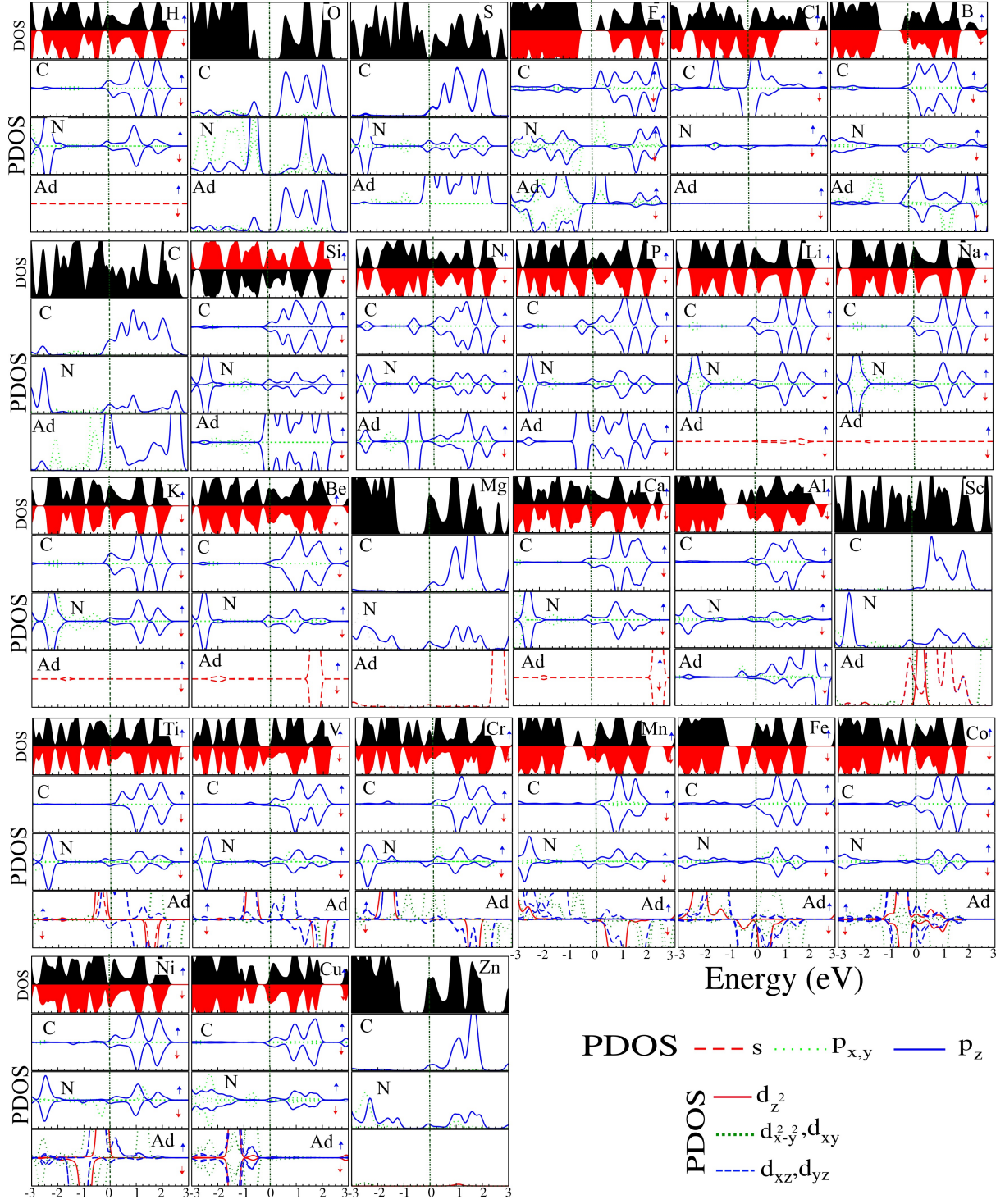


Figure 1: DOS and PDOS of different atoms embedded into the holey site of the  $C_6N_8$  monolayer. The zero of energy is set at  $E_F$ .